## *Praetorian*<sup>®</sup> L-C EMI Filter with ESD Protection for Headset Speaker Applications

#### Features

- 2 channels of EMI filtering
- ±8kV ESD protection (IEC 61000-4-2, contact discharge)
- ±15kV ESD protection (HBM)
- Greater than -40dB of attenuation at 1GHz
- TDFN-08 package

### **Applications**

- Headset Speaker port in mobile handsets
- I/O port protection for mobile handsets, notebook computers, PDAs, etc.
- EMI filtering for data ports in cell phones, PDAs or notebook computers

### **Product Description**

California Micro Devices' CM1483 is an L-C EMI filter array with ESD protection, which integrates two Pifilters (C-L-C) for the headset speaker. The CM1483 has component values of 100pF-3nH-100pF. The parts include ESD protection diodes on all input/output pins, which provide a very high level of protection for sensitive electronic components that may be subjected to electrostatic discharge (ESD). The ESD diodes connected to the filter ports safely dissipate ESD strikes of  $\pm 8$ kV, beyond the maximum requirement of the IEC61000-4-2 international standard. Using the MIL-STD-883 (Method 3015) specification for Human Body Model (HBM) ESD, the pins are protected for contact discharges at greater than  $\pm 15$ kV.

This device is particularly well suited for portable electronics (e.g. mobile handsets, PDAs, notebook computers) because of its small package format and easy-to-use pin assignments. In particular, the CM1483 is ideal for EMI filtering and protecting speaker output lines from ESD for the headset speaker in mobile handsets. Most speakers have impedance of  $8\Omega$  and in order to maximize the power output, the resistance of an EMI filter needs to be as low as possible and the CM1483 addresses this by having a C-L-C based EMI filter where the inductor has less than  $1\Omega$  of resistance.

The CM1483 is available in a small, low-profile (2mm x 2mm) 8-lead TDFN package in a lead-free finish.

#### **Electrical Schematic**



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PIN DESCRIPTIONS				
PIN	NAME	DESCRIPTION		
1	Filter #1	Filter #1		
2	NC	No connect		
3	NC	No connect		
4	Filter #2	Filter #2		
5	Filter #2	Filter #2		
6	NC	No connect		
7	NC	No connect		
8	Filter #1	Filter #1		
DAP	GND	Ground		

## **Ordering Information**

PART NUMBERING INFORMATION					
		Lead-free Finish			
Pins	Package	Ordering Part Number <sup>1</sup>	Part Marking		
8	TDFN	CM1483-02DE	83E		

Note 1: Parts are shipped in Tape & Reel form unless otherwise specified.

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## Specifications

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	RATING	UNITS			
Storage Temperature Range	-65 to +150	°C			
DC current per inductor	30	mA			
DC package power rating	0.5	W			

STANDARD OPERATING CONDITIONS				
PARAMETER	RATING	UNITS		
Operating Temperature Range	-40 to +85	°C		

ELECTRICAL OPERATING CHARACTERISTICS (NOTE 1)							
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
L	Inductance	Note 3		3.0		nH	
R	DC Channel Resistance	Note 3		0.75	1	Ω	
C <sub>TOT</sub>	Total Channel Capacitance	2.5V DC; 1MHz, 30mV AC	160	200	240	pF	
С	Capacitance C	2.5V DC; 1MHz, 30mV AC		100		pF	
I <sub>LEAK</sub>	Diode Leakage Current	V <sub>IN</sub> = +5V		0.1	1.0	μA	
		V <sub>IN</sub> =-5V		-1.0	0.1	μA	
V <sub>SIG</sub>	Signal Clamp Voltage Positive Clamp Negative Clamp	$I_{LOAD} = 10mA$ $I_{LOAD} = -10mA$	5 –15	7 –10	15 –5	V V	
V <sub>ESD</sub>	In-system ESD Withstand Voltage Human Body Model, MIL-STD-883, Method 3015 Contact Discharge per IEC 61000- 4-2 Level 4	Notes 2 & 3	±15 ±8			kV kV	
f <sub>C</sub>	Cut-off frequency $Z_{SOURCE} = 50\Omega$ , $Z_{LOAD} = 50\Omega$	L = 3nH, C = 100pF		31		MHz	

Note 1:  $T_A = 25^{\circ}C$  unless otherwise specified.

Note 2: ESD applied to input and output pins with respect to GND, one at a time.

Note 3: These parameters guaranteed by design and characterization.

## **Performance Information**

Typical Filter Performance (nominal conditions unless specified otherwise, 50 ohm environment)







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#### **Mechanical Details**

#### **TDFN-08 Mechanical Specifications, 0.5mm**

The CM1483 is supplied in an 8-lead 0.5mm TDFN package. Dimensions are presented below.

For complete information on the TDFN-08, see the California Micro Devices TDFN Package Information document.

PACKAGE DIMENSIONS							
Package	TDFN						
JEDEC No.	MO-229 (Var. VCCD-3) <sup>*</sup>						
Leads	8						
Dim	Millimeters			Inches			
Dini.	Min	Nom	Max	Min	Nom	Max	
Α	0.70	0.75	0.80	0.028	0.028 0.030 0.03		
A3	0.20 REF			0.008 REF			
b	0.20	0.25	0.30	0.008	0.010	0.012	
D	1.90	2.00	2.10	0.075	0.079	0.083	
D2	1.50	1.60	1.70	0.059	0.063	0.067	
E	1.90	2.00	2.10	0.075	0.079	0.083	
E2	0.80	0.90	1.00	0.031	0.035	0.039	
е	0.50 BSC			0.020 BSC			
К	0.20			0.008			
L	0.20	0.30	0.40	0.008	0.012	0.016	
# per tape and reel	3000 pieces						
Controlling dimension: millimeters							

<sup>\*</sup>This package is compliant with JEDEC standard MO-229, variation VCCD-3 with exception of the D2 and E2 dimensions as called out in the table above and the r1 dimension which is not specified in the MO-229 standard.



# Package Dimensions for 8-Lead, 0.5mm pitch TDFN package

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